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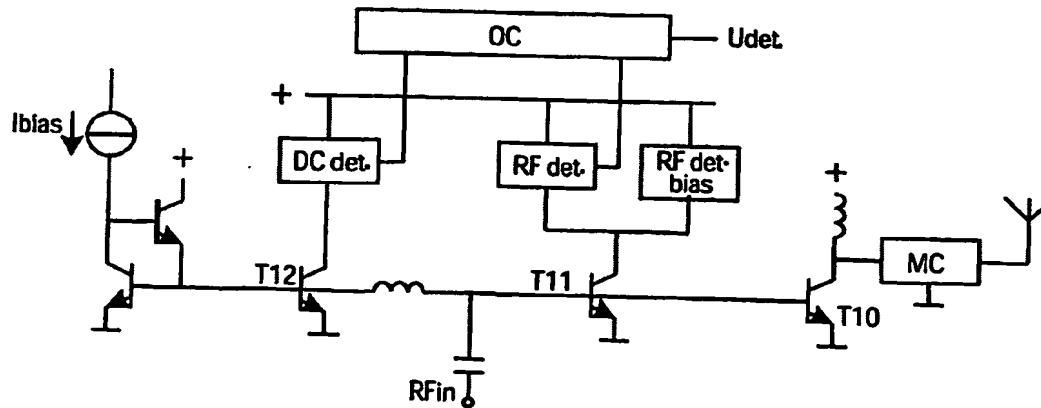
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(54) Title: OUTPUT POWER DETECTION CIRCUIT



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(57) Abstract: A detection circuit for detecting the output power of a power amplifier comprises a first current mirror transistor (T11) having a base, which is connectable to a power transistor (T10), and a collector, a RF detection means (RF-det) for detecting the RF current flowing through the current mirror transistor (T11). Said RF detection means (RF-det) is connected to the collector of said first current mirror transistor (T11). Said detection circuit further comprises a biasing means (bias-RF-det) for biasing said RF detection means (RF-det), wherein said biasing means is connected to said collector of said first current mirror (T11) and said RF detection means (RF-det).